

<u>1000V 15A</u> APT15D100K APT15D100KG\*

\*G Denotes RoHS Compliant, Pb Free Terminal Finish. 

# ULTRAFAST SOFT RECOVERY RECTIFIER DIODE

#### **PRODUCT APPLICATIONS**

- Anti-Parallel Diode -Switchmode Power Supply -Inverters
- Free Wheeling Diode -Motor Controllers -Converters -Inverters

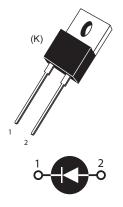
- Snubber Diode
- PFC

#### PRODUCT FEATURES

- Ultrafast Recovery Times
- Soft Recovery Characteristics
- · Popular TO-220 Package
- Low Forward Voltage
- · Low Leakage Current

### PRODUCT BENEFITS

- Low Losses
- · Low Noise Switching
- Cooler Operation
- · Higher Reliability Systems
- Increased System Power Density



1 - Cathode 2 - Anode Back of Case - Cathode

## MAXIMUM RATINGS

<b>MAXIMUM RATINGS</b> All Ratings: $T_c = 25^{\circ}C$ unless other			
Symbol	Characteristic / Test Conditions	APT15D100K(G)	UNIT
V <sub>R</sub>	Maximum D.C. Reverse Voltage		
V <sub>RRM</sub>	Maximum Peak Repetitive Reverse Voltage	1000	Volts
V <sub>RWM</sub>	Maximum Working Peak Reverse Voltage		
I <sub>F(AV)</sub>	Maximum Average Forward Current ( $T_c = 130^{\circ}C$ , Duty Cycle = 0.5)	15	
I <sub>F(RMS)</sub>	RMS Forward Current (Square wave, 50% duty)	31	Amps
I <sub>FSM</sub>	Non-Repetitive Forward Surge Current $(T_J = 45^{\circ}C, 8.3ms)$	80	
T <sub>J</sub> ,T <sub>STG</sub>	Operating and StorageTemperature Range	-55 to 175	J°
Τ <sub>L</sub>	Lead Temperature for 10 Sec.	300	

#### STATIC ELECTRICAL CHARACTERISTICS

Symbol	Characteristic / Test Conditions		MIN	ТҮР	МАХ	UNIT
V <sub>F</sub>	Forward Voltage	I <sub>F</sub> = 15A		1.9	2.3	Volts
		I <sub>F</sub> = 30A		2.2		
		I <sub>F</sub> = 15A, T <sub>J</sub> = 125°C		1.7		
I <sub>RM</sub>	Maximum Reverse Leakage Current	$V_R = V_R Rated$			250	μA
		$V_R = V_R$ Rated, $T_J = 125^{\circ}C$			500	
C <sub>T</sub>	Junction Capacitance, $V_R = 200V$			17		pF

### **DYNAMIC CHARACTERISTICS**

## APT15D100K(G)

Symbol	Characteristic	Test Conditions	MIN	ТҮР	MAX	UNIT
t <sub>rr</sub>	Reverse Recovery Time $I_F = 1A$ , $di_F/dt = -100A/\mu s$ , $V_R = 30V$ , $T_J = 25^{\circ}C$		-	28		ns
t <sub>rr</sub>	Reverse Recovery Time	I <sub>F</sub> = 15A, di <sub>F</sub> /dt = -200A/μs V <sub>R</sub> = 667V, T <sub>C</sub> = 25°C	-	260		115
Q <sub>rr</sub>	Reverse Recovery Charge		-	540		nC
I <sub>RRM</sub>	Maximum Reverse Recovery Current		-	4	-	Amps
t <sub>rr</sub>	Reverse Recovery Time	I <sub>F</sub> = 15A, di <sub>F</sub> /dt = -200A/μs V <sub>R</sub> = 667V, T <sub>C</sub> = 125°C	-	300		ns
Q <sub>rr</sub>	Reverse Recovery Charge		-	1550		nC
I <sub>RRM</sub>	Maximum Reverse Recovery Current		-	9	-	Amps
t <sub>rr</sub>	Reverse Recovery Time	I <sub>F</sub> = 15A, di <sub>F</sub> /dt = -1000A/µs V <sub>R</sub> = 667V, T <sub>C</sub> = 125°C	-	150		ns
Q <sub>rr</sub>	Reverse Recovery Charge		-	2150		nC
I <sub>RRM</sub>	Maximum Reverse Recovery Current		-	26		Amps

#### THERMAL AND MECHANICAL CHARACTERISTICS

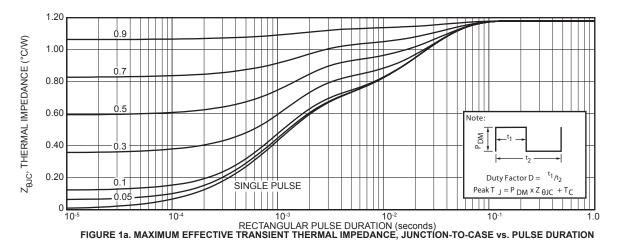
Symbol	Characteristic / Test Conditions	MIN	TYP	MAX	UNIT
R <sub>eJC</sub>	Junction-to-Case Thermal Resistance			1.18	°C/W
R <sub>θJA</sub>	Junction-to-Ambient Thermal Resistance			80	
W <sub>T</sub>	Package Weight		0.07		oz
			1.9		g
Torque	Maximum Mounting Torque			10	lb•in
				1.1	N•m

Microsemi Reserves the right to change, without notice, the specifications and information contained herein.

Junction temp(°C)

Case temperatur e (°C)

Power (watts)



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FIGURE 1b, TRANSIENT THERMAL IMPEDANCE MODEL

RC MODE L

0.676 °C/W

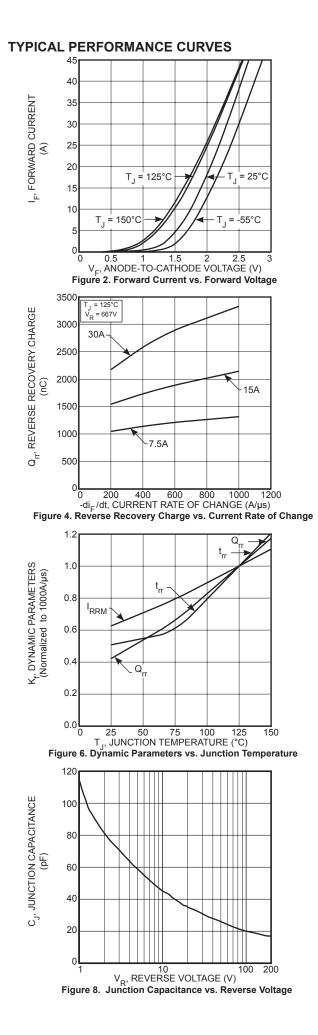
0.504 °C/W

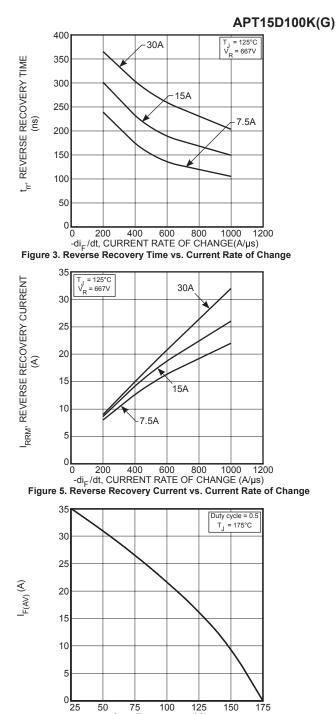
0.00147 J/ °C

0.0440 J/ °C

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Case Temperature (°C) Figure 7. Maximum Average Forward Current vs. CaseTemperature

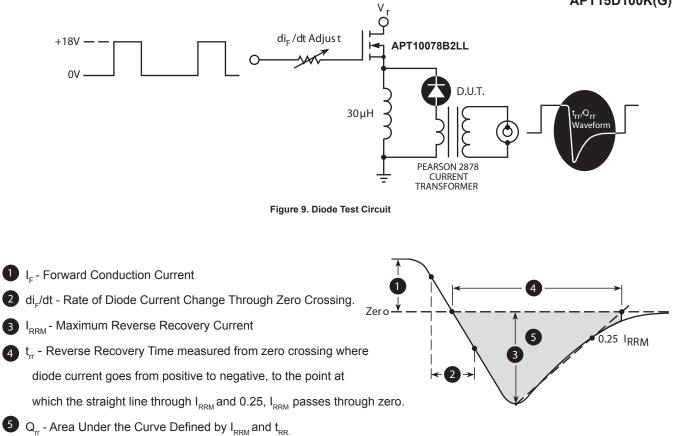
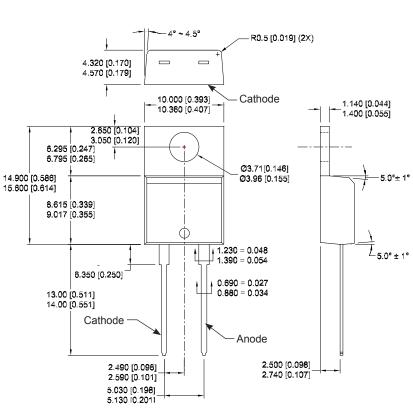


Figure 10. Diode Reverse Recovery Waveform Definition



TO-220 (K) Package Outline

e3 100% Sn

Dimensions in millimeters and [inches]

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